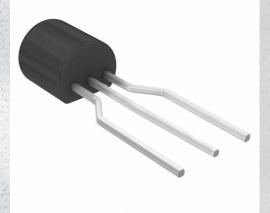


2N3904TAR Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	2N3904TAR-DG
Manufacturer	onsemi
Manufacturer Product Number	2N3904TAR
Description	TRANS NPN 40V 0.2A TO92-3
Detailed Description	Bipolar (BJT) Transistor NPN 40 V 200 mA 300MHz 6 25 mW Through Hole TO-92-3

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
2N3904TAR	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	200 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
40 V	300mV @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
-	100 @ 10mA, 1V
Power - Max:	Frequency - Transition:
625 mW	300MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 (TO-226AA) Formed Leads	TO-92-3
Base Product Number:	
2N3904	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	Not Applicable
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	



Is Now Part of

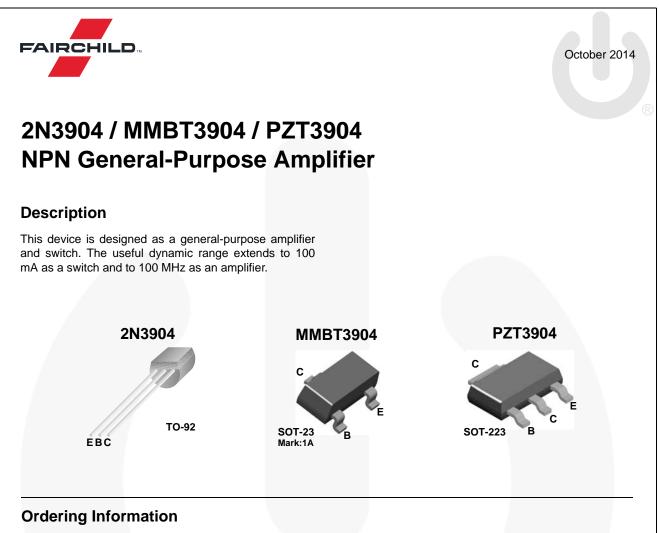


ON Semiconductor[®]

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Part Number	Marking	Package	Packing Method	Pack Quantity
2N3904BU	2N3904	TO-92 3L	Bulk	10000
2N3904TA	2N3904	TO-92 3L	Ammo	2000
2N3904TAR	2N3904	TO-92 3L	Ammo	2000
2N3904TF	2N3904	TO-92 3L	Tape and Reel	2000
2N3904TFR	2N3904	TO-92 3L	Tape and Reel	2000
MMBT3904	1A	SOT-23 3L	Tape and Reel	3000
PZT3904	3904	SOT-223 4L	Tape and Reel	2500

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
۱ _C	Collector Current - Continuous	200	mA
$T_{J,}T_{STG}$	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904 ⁽³⁾	PZT3904 ⁽⁴⁾	Onit
PD	Total Device Dissipation	625	350	1,000	mW
۳D	Derate Above 25°C	5.0	2.8	8.0	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3			°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.

4. Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum 6 cm².

Electrical Characteristics

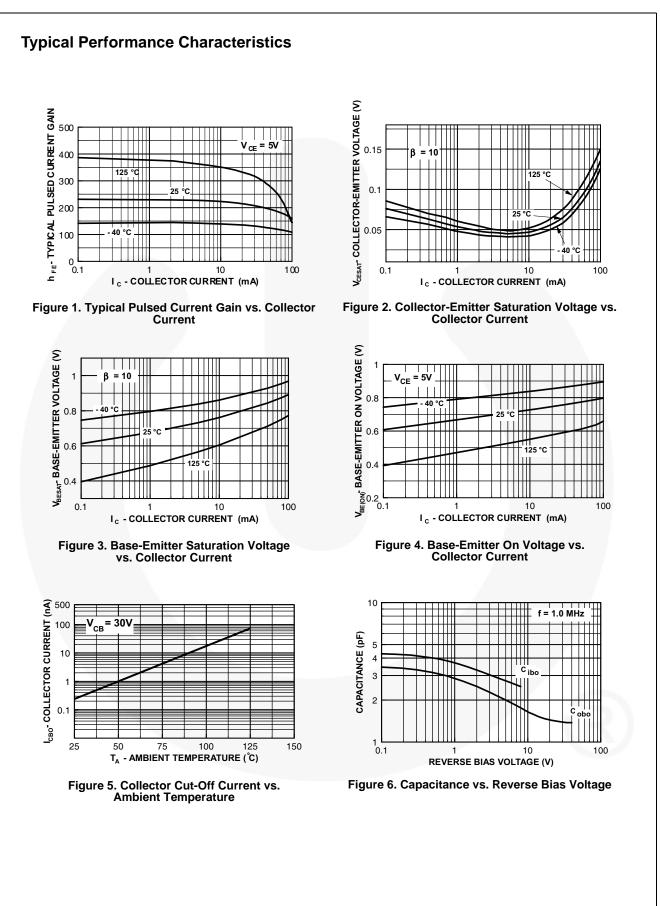
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
OFF CHAR	ACTERISTICS		•	•	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1.0 mA, I _B = 0	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu \text{A}, \ I_{\rm E} = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	6.0		V
I _{BL}	Base Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA
I _{CEX}	Collector Cut-Off Current	V _{CE} = 30 V, V _{EB} = 3 V		50	nA
ON CHARA	CTERISTICS ⁽⁵⁾				
		$I_{C} = 0.1 \text{ mA}, V_{CE} = 1.0 \text{ V}$	40		
		I _C = 1.0 mA, V _{CE} = 1.0 V	70		
h _{FE}	DC Current Gain	I _C = 10 mA, V _{CE} = 1.0 V	100	300	
		I _C = 50 mA, V _{CE} = 1.0 V	60		
		I _C =100 mA, V _{CE} = 1.0V	30		
V (act)	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA		0.2	V
V _{CE} (sat)		I _C = 50 mA, I _B = 5.0 mA		0.3	- V
V/ (aat)	Base-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA	0.65	0.85	
V _{BE} (sat)		I _C = 50 mA, I _B = 5.0 mA		0.95	
SMALL SIG	NAL CHARACTERISTICS			•	
f _T	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	300		MHz
C _{obo}	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.0	pF
C _{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0,$ f = 100 kHz		8.0	pF
NF	Noise Figure	$ I_{C} = 100 \ \mu\text{A}, \ V_{CE} = 5.0 \ \text{V}, \\ R_{S} = 1.0 \ \text{k}\Omega, \\ f = 10 \ \text{Hz} \ \text{to} \ 15.7 \ \text{kHz} $		5.0	dB
SWITCHING	CHARACTERISTICS	•			
t _d	Delay Time	V _{CC} = 3.0 V, V _{BE} = 0.5 V		35	ns
t _r	Rise Time	$I_{\rm C} = 10 \text{ mA}, I_{\rm B1} = 1.0 \text{ mA}$		35	ns
t _s	Storage Time	$V_{CC} = 3.0 \text{ V}, I_{C} = 10 \text{ mA},$		200	ns
t _f	Fall Time	$I_{B1} = I_{B2} = 1.0 \text{ mA}$		50	ns

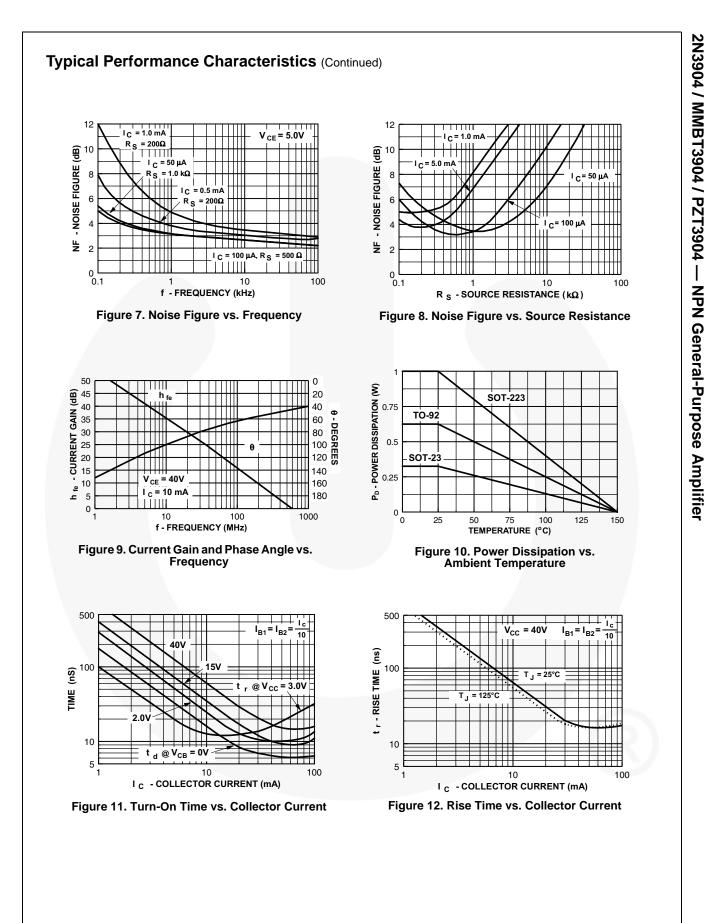
Note:

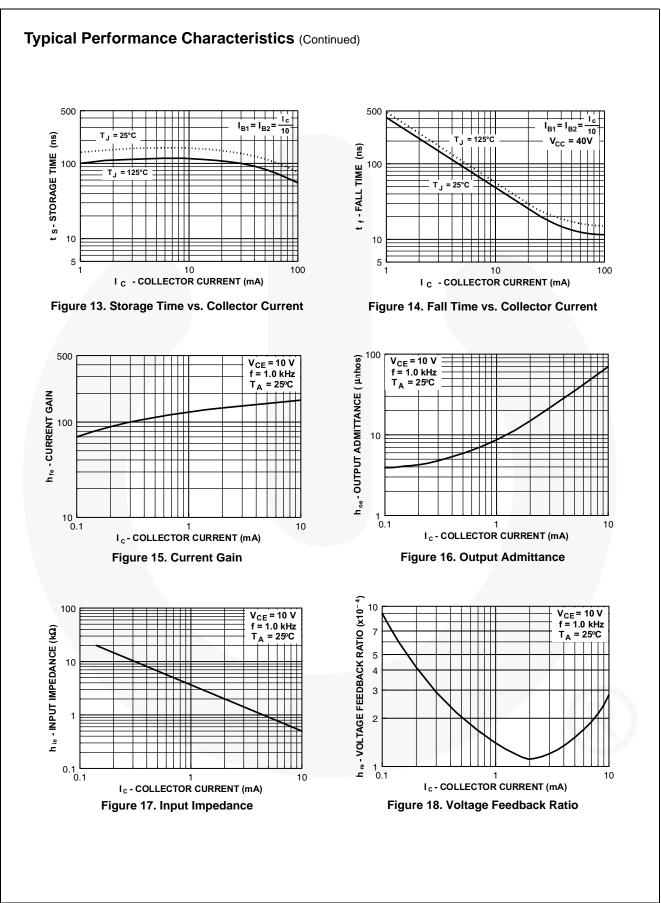
5. Pulse test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2.0%.

2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier

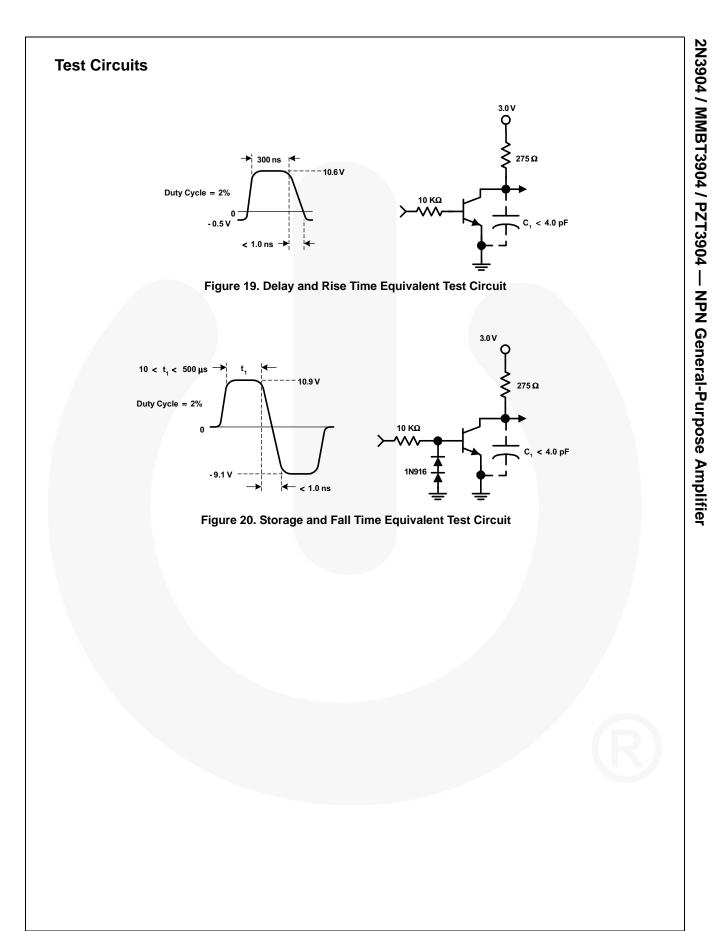


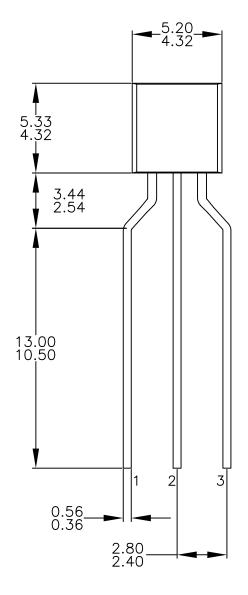
2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier

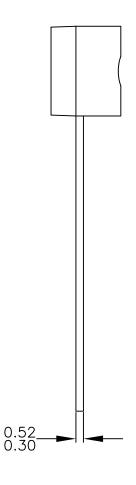




2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier

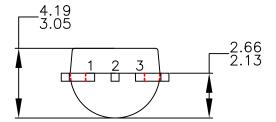


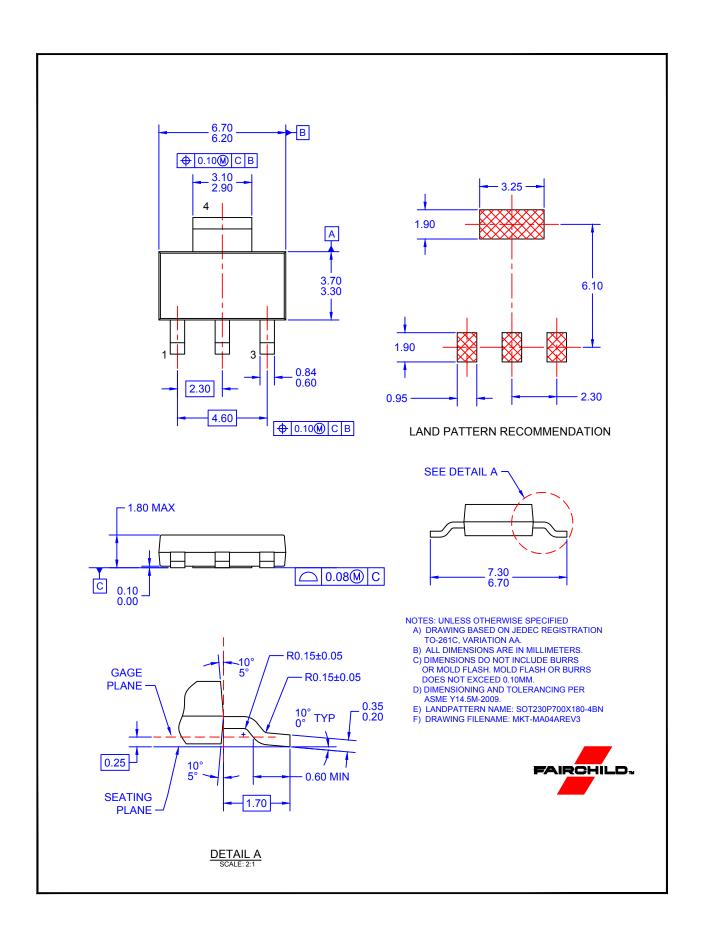


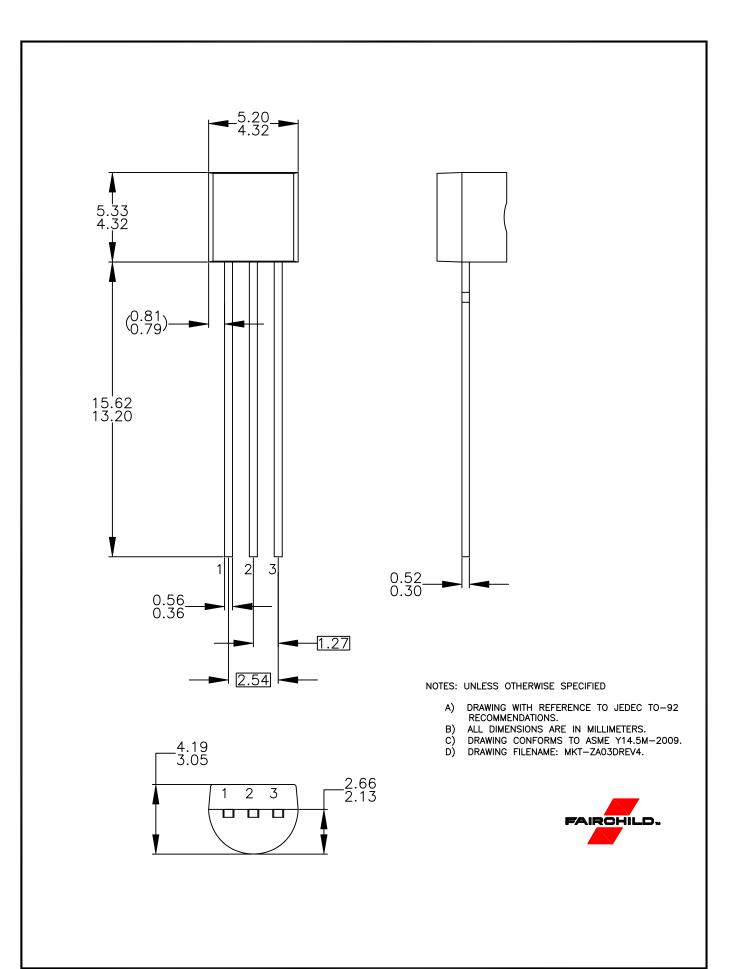


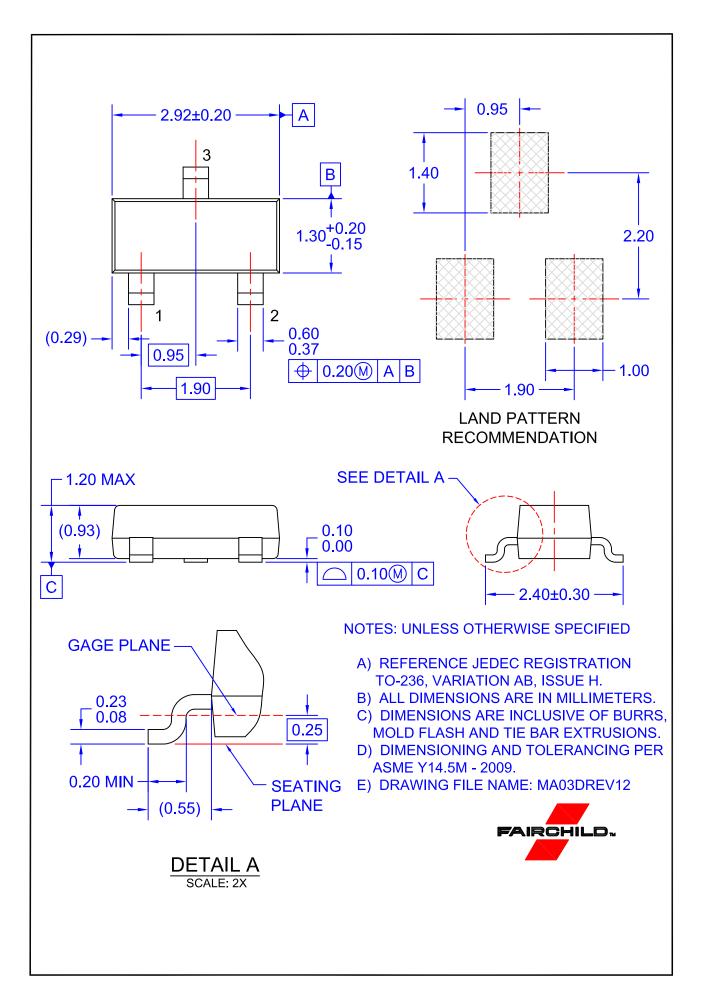
NOTES: UNLESS OTHERWISE SPECIFIED

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- В. С. D. Е.









2N3904TAR onsemi TRANS NPN 40V 0.2A TO92-3

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